

# Gamma ray irradiation induced point defects in BaF<sub>2</sub>\*

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**Abstract** There are some original nonmagnetic point defects in the BaF<sub>2</sub> crystallite powder, such as interstitial and vacant F<sup>-</sup> which can become paramagnetic centers by  $\gamma$ -ray-irradiation at room temperature. After  $\gamma$ -ray irradiation the paramagnetic point defects V<sub>k</sub>, H, F and M centers, have been observed in the sample with experiment of electron spin resonance (ESR). Frenkel exciton, a nonmagnetic point defect, can also be induced by the  $\gamma$ -ray irradiation in the sample at room temperature, the existence of the Frenkel exciton is affirmed by an anomalous change of the ESR signal of V<sub>k</sub> center with temperature. The signals of the ESR of the H, F and M centers weaken and vanish with the temperature increasing monotonously. But the ESR signal of the V<sub>k</sub> enhances when the temperature goes up about 127°C, then weakens and vanishes. An increase in the V<sub>k</sub> center follows an annihilation of the Frenkel exciton with heating.

**Keywords** Gamma-ray irradiation, Frenkel exciton, Paramagnetic point defect, V<sub>k</sub> center

## 1 Introduction

In many years W. Hayes and P. J. Call *et al.* have devoted themselves to the studies of point defects in alkaline earth fluoride crystals and of defects produced by irradiation<sup>[1,2]</sup> with electron spin resonance (ESR) method. ESR has been proved to be a very sensitive, reliable and important technique for the studies of point defects in solid materials. The point defects of paramagnetic color centers produced by the  $\gamma$ -ray and X-ray irradiations are mainly: F center (an electron trapped by anion vacancy), V<sub>k</sub> center (self-trapped hole center, or a hole trapped by a lattice anion), H center (a hole trapped by an interstitial anion) and M center (adjacency of two F centers). In many cases the V<sub>k</sub> center is complementary to the F center<sup>[1]</sup>. In BaF<sub>2</sub> the F center is an electron trapped by F<sup>-</sup> vacancy, the V<sub>k</sub> center is a F<sup>0</sup> at lattice site, the H center is a F<sup>0</sup> at interstitial site, and the M center is a pair of electrons trapped by two adjacent F<sup>-</sup> ions vacancies.

Barium halide possesses some excellent luminescence properties to which much attention has been paid, they doped with rare earth are being studied widely for the  $\gamma$ -ray detection and X-ray image storage materials. The BaF<sub>2</sub> is a very nice detection material for high-energy particles, its irradiation effect is of considerable

interest both from the research viewpoint and that of applications. Its ESR spectra are similar to those of BaCl<sub>2</sub>. Comparing ESR spectra of BaCl<sub>2</sub><sup>[3]</sup> and BaF<sub>2</sub>, we found existence of the Frenkel exciton.

## 2 Experiments

Three samples are studied. The sample #1 is BaF<sub>2</sub> crystallite powder, the sample #2 is abrasive powder of the BaF<sub>2</sub> single crystal, the sample #3 is BaF<sub>2</sub> single crystal. The ESR experiments were carried out at room temperature, the samples were heated from 18°C to 420°C. The microwave frequency  $f$  was 9.4588 GHz. The <sup>60</sup>Co source was used for  $\gamma$ -ray-irradiation at room temperature, the radiation dose rate was 103.3 Gy/min.

## 3 Results and analysis

No ESR signal has been observed before  $\gamma$ -ray irradiation in the three samples, so the ESR signals observed after  $\gamma$ -ray irradiation in the sample #1 and #2 stem from irradiation induced paramagnetic point defects without doubt. There are four peaks in the sample #1 with  $\Delta H_{pp}$  about 2–4 mT after  $\gamma$ -ray-irradiation for 30 min; there is quite a wide peak in the sample #2 with  $\Delta H_{pp}$  of 43.5 mT

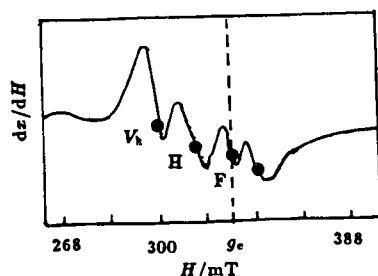
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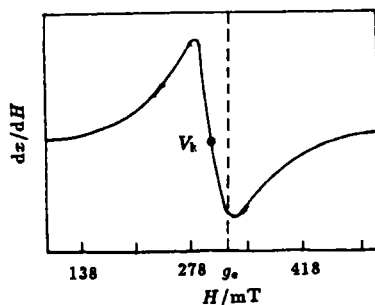
for 5 min  $\gamma$ -ray-irradiation. There is still no ESR peak in the sample #3 for 30 min  $\gamma$ -ray-irradiation, the reason might be that the point defects locate often at the surface of grains, the sample #3 is perfect crystal, the surface per unit mass is much less than those of the sample #1 and #2, and the irradiated defects annihilate below room temperature<sup>[1,2]</sup>. On the other hand, after  $\gamma$ -ray irradiation, there is still no ESR signal in the sample #3. It is to say, there are original nonmagnetic point defects in the samples of the  $\text{BaF}_2$  crystallite powder and abrasive powder of the  $\text{BaF}_2$  single crystal, such as interstitial and vacant  $\text{F}^-$  which are located mainly at the surface and boundary plane of crystallite grains, and these nonmagnetic point defects can become paramagnetic centers by  $\gamma$ -ray-irradiation at room tempera-

ture.

The ESR spectra of the samples #1 and #2 at room temperature are shown in Fig.1 and Fig.2. The values of the  $g$  factor of the ESR signals are determined with a standard sample DPPH ( $g=2.0037$ ). These  $g$  values are compared with  $g_e$  of free electron (2.0023), and with ESR spectra of irradiated  $\text{BaCl}_2$  crystallite<sup>[3]</sup>; the four ESR peaks in the sample #1 are affirmed<sup>[4]</sup>, they are  $V_k$  ( $g=2.2022$ ), H (2.0834), F (1.9884) and M [ $g=(1.9884+1.9426)/2=1.9655$ ] in the sample #1. The intensities of ESR signals of the H, K and M are weakened with temperature increasing monotonously, and that of H vanishes at  $67^\circ\text{C}$ , those of the K and M at  $150^\circ\text{C}$ , because the crystalline grain tends to perfection, and the defects annihilate with heating and time<sup>[4]</sup>.



**Fig.1** The ESR spectra of  $\text{BaF}_2$  crystallite powder (sample #1) after  $\gamma$ -ray irradiation



**Fig.2** The ESR spectra of abrasive powder of the  $\text{BaF}_2$  single crystal (sample #2) after  $\gamma$ -ray irradiation

It is found that the ESR signal of  $V_k$  center does not decline monotonously with the temperature increasing as those of the H, F and M centers do, the change of its intensity with temperature is not monotonous, the intensity enhances when the temperature goes up to  $127^\circ\text{C}$  (it shows the number of the  $V_k$  center increases), then weakens, and vanishes at not higher than  $350^\circ\text{C}$  (it is annihilation of the  $V_k$  center). The ESR signal of  $V_k$  center in  $\text{BaCl}_2$  is weakened with temperature increasing monotonously, and vanishes at  $71^\circ\text{C}$ <sup>[3]</sup>. The dependences of the intensities of the ESR signals of  $V_k$  center in  $\text{BaF}_2$  and  $\text{BaCl}_2$  on the tem-

perature are shown in Fig.3.

The ESR signal is a wide peak with  $\Delta H_{pp}$  about 43.5 mT and  $g=2.2212$  in the sample #2. The change of intensity of ESR signal with temperature is also not monotonous, the intensity of the signal enhances when the temperature goes up below  $100^\circ\text{C}$ , it nearly does not change at  $100\sim 200^\circ\text{C}$ , then weakens, and vanishes at  $420^\circ\text{C}$ . The signal is also of  $V_k$  center, the sample #2 is abrasive powder of the  $\text{BaF}_2$  single crystal, the anion vacancy is at the surface of the grains, and there is no interstitial anion, so no H, F and M centers. Details of the experi-

ment and analysis are described in Ref.[4].

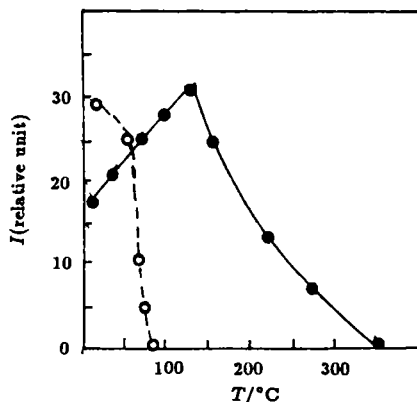


Fig.3 The dependence of the intensities of the ESR signals of  $V_k$  center in BaF<sub>2</sub> and BaCl<sub>2</sub> on the temperature

Solid line is of BaF<sub>2</sub>, the dashed line is of BaCl<sub>2</sub>

The phenomenon that the ESR signal of the  $V_k$  enhances with temperature increasing in the samples #1 and #2, is related to the Frenkel exciton excited by the  $\gamma$ -ray irradiation in BaF<sub>2</sub>. C. S. Shi *et al* had found this exciton with experimentation of an absorption spectrum<sup>[5]</sup>, the gap energy is 10.9 eV, and the exciton binding energy is 1.1 eV. A Frenkel exciton is a tightly bound electron-hole pair, it is called an elementary excitation or an excited state of a single atom. It is induced as an electron of 2p of  $F^-$  ion is excited to a higher level of outer shell orbit by the  $\gamma$ -ray irradiation, and the electron is coupled with the hole of the 2p orbit. When the electron in the Frenkel exciton gets energy from heating, and leaves the  $F^-$  ion, the  $F^-$  becomes  $F^0$ , a  $V_k$  center, that is to say, the ESR signal of the  $V_k$  centers enhances as the temperature increasing, it shows

annihilation of the Frenkel exciton and creation of the  $V_k$  center. Owing to the existence of the Frenkel excitons excited by  $\gamma$ -ray irradiation, the exciton is nonmagnetic, and it can not be detected with ESR, but can become a  $V_k$  center with heating. It is the reason why the ESR signal of the  $V_k$  center does not decline monotonously with the temperature increasing as those of the H, F and M centers do. The ESR signal of the  $V_k$  center enhances as the temperature increasing, it is a witness to annihilation of the Frenkel exciton. The difference of BaCl<sub>2</sub> from BaF<sub>2</sub> is that the attraction of the Cl atom to electron is more weaker than that of F atom, so Frenkel exciton can not form in BaCl<sub>2</sub>.

The  $\gamma$ -ray irradiation induced the paramagnetic point defects  $V_k$ , H, F and M centers in the sample #1, and the  $V_k$  in the sample #2. Nonmagnetic Frenkel exciton can also be induced by the  $\gamma$ -ray irradiation at room temperature. It is noticed that annihilation of the Frenkel exciton emerges the  $V_k$  center, so one should pay much attention to the irradiated characteristic of BaF<sub>2</sub> crystallite powder in its application.

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